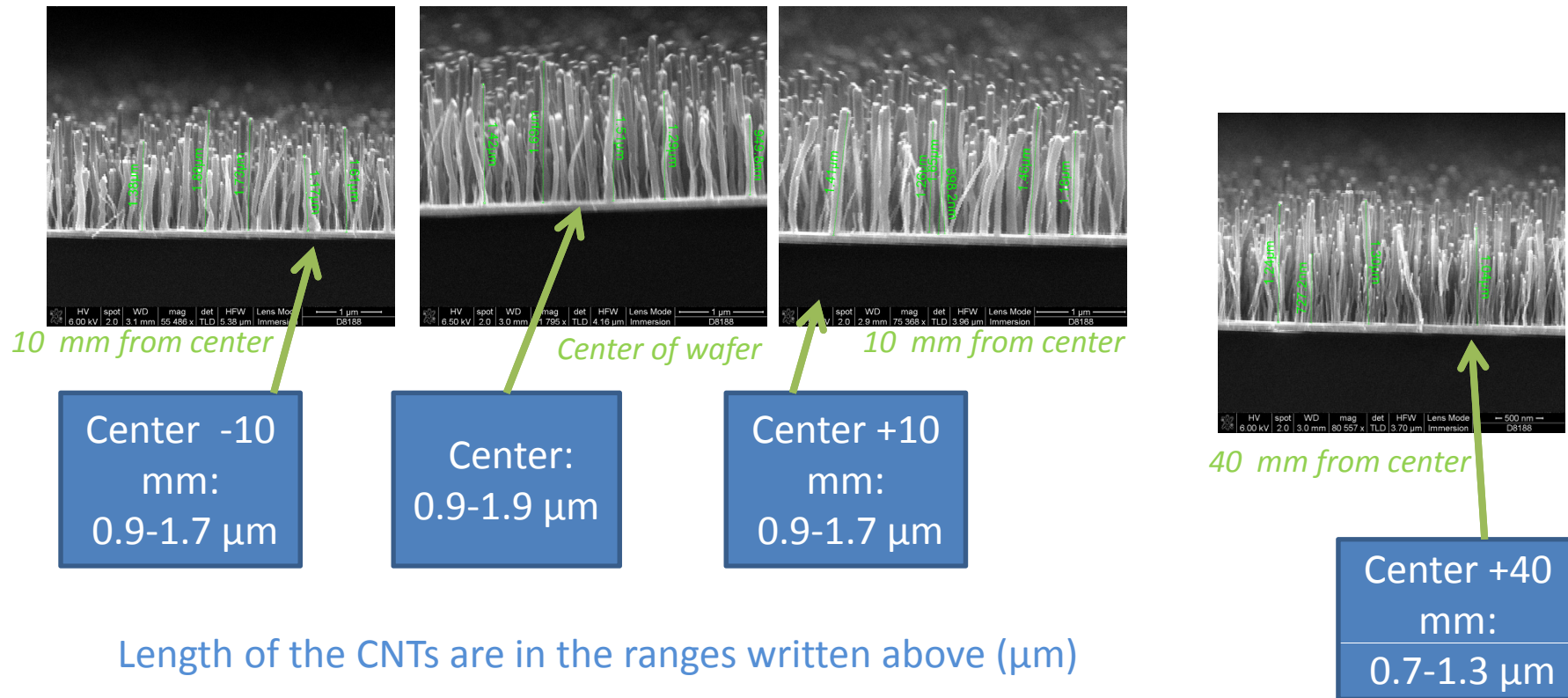


Length of CNTs on one wafer: 4 measurement points on the wafer

Another wafer



Process parameters Recipe: PECVD NH3.txt ; Growth time: 5 min

Gasses growth: N2:100 sccm NH3:160 C2H2:40; **Substrate:** Si/TiW/Ni (100 nm TiW/7 nm Ni)

(Wafer 5)